



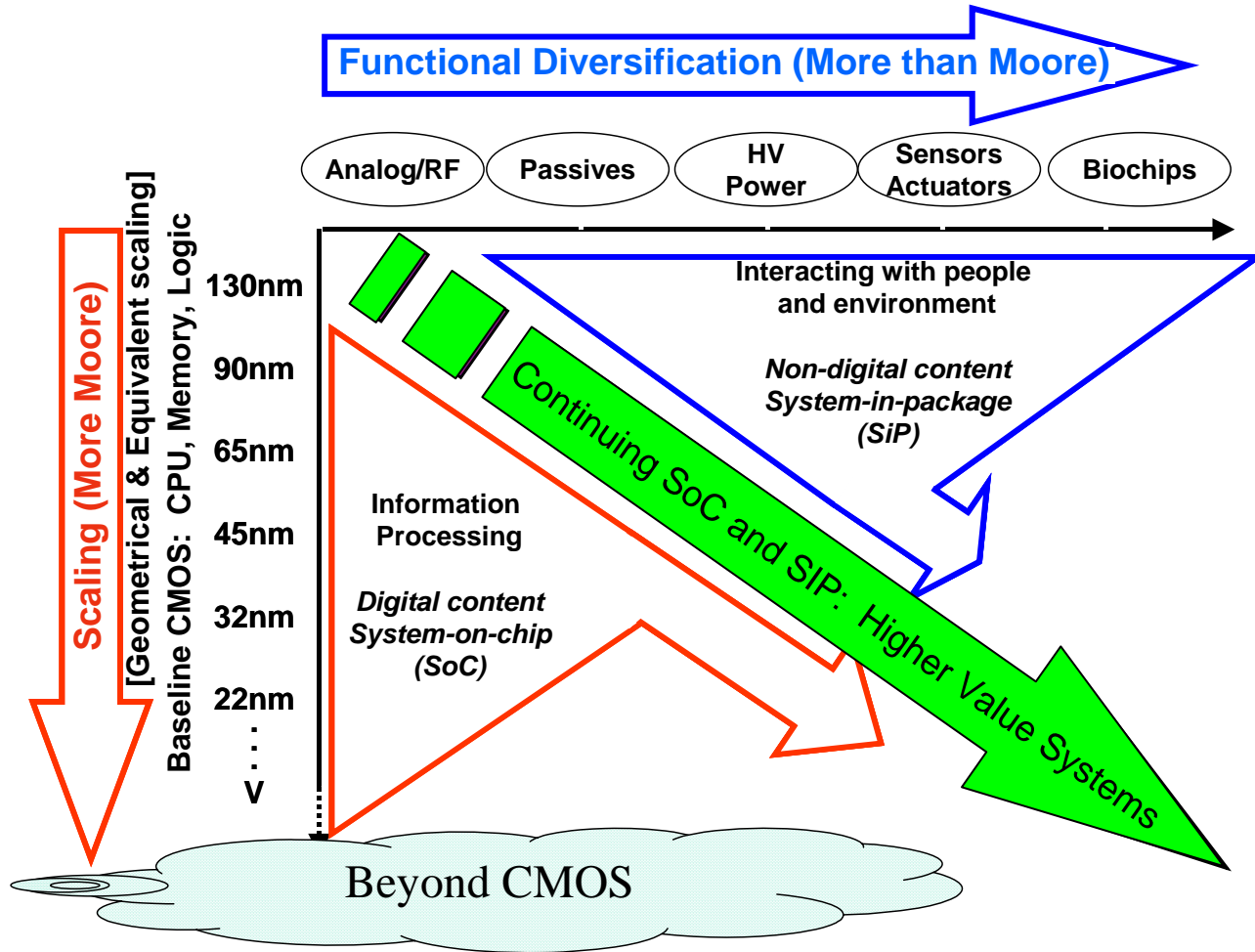
International Technology Roadmap for Semiconductors

MORE THAN MOORE

MORE THAN MOORE: *What is It?*

MART GRAEF
IRC – ESIA, Europe

Moore's Law & More



2007 ITRS “Moore’s Law and More” Definition Graphic Proposal

*Baseline
CMOS*

Memory

RF

*HV
Power*

Passives

*Sensors,
Actuators*

*Bio-chips,
Fluidics*

“More Moore”

“More than Moore”

Computing &
Data Storage

Sense, interact,
Empower

Heterogeneous Integration

System on Chip (SOC) and System In Package (SIP)

Source: ITRS, European Nanoelectronics Initiative Advisory Council (ENIAC)

“More Moore” and “More than Moore”

- **“More Moore”**: **Scaling**

Continued shrinking of physical feature sizes of the *digital* functionalities (logic and memory storage) in order to improve *density* (cost per function reduction) and *performance* (speed, power).

- **“More than Moore”**: **Functional Diversification**

Incorporation into devices of functionalities that do not necessarily scale according to "Moore's Law", but provide additional value in different ways. The "More-than-Moore" approach allows for the *non-digital* functionalities to migrate from the system board-level into the package (SiP) or onto the chip (SoC).

- **The Challenge: Integration of MM with MtM**

Creation of intelligent compact systems.

MORE THAN MOORE

Why the Market Cares...

PUSHKAR APTE
IRC – SIA, USA

Semiconductor Growth: 2007



2007
Cell Phone Shipments
+10% (units)



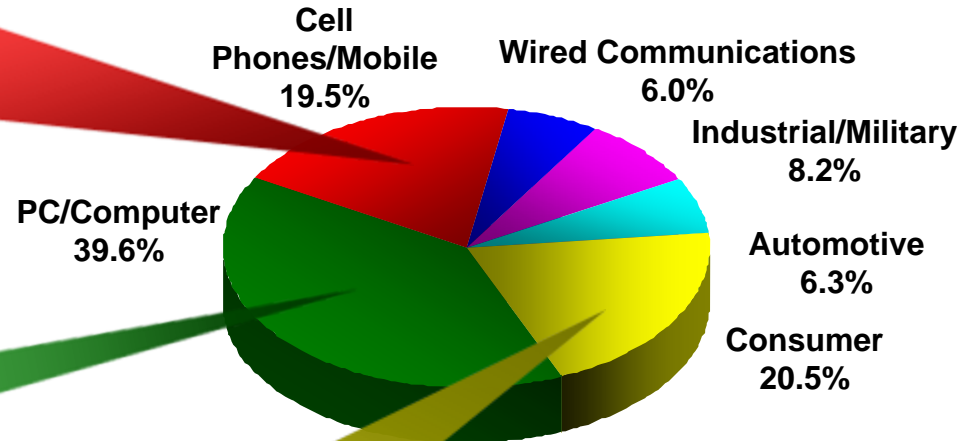
2007
PC Shipments
+10% (Units)



2007
Digital TV
+51% (Units)



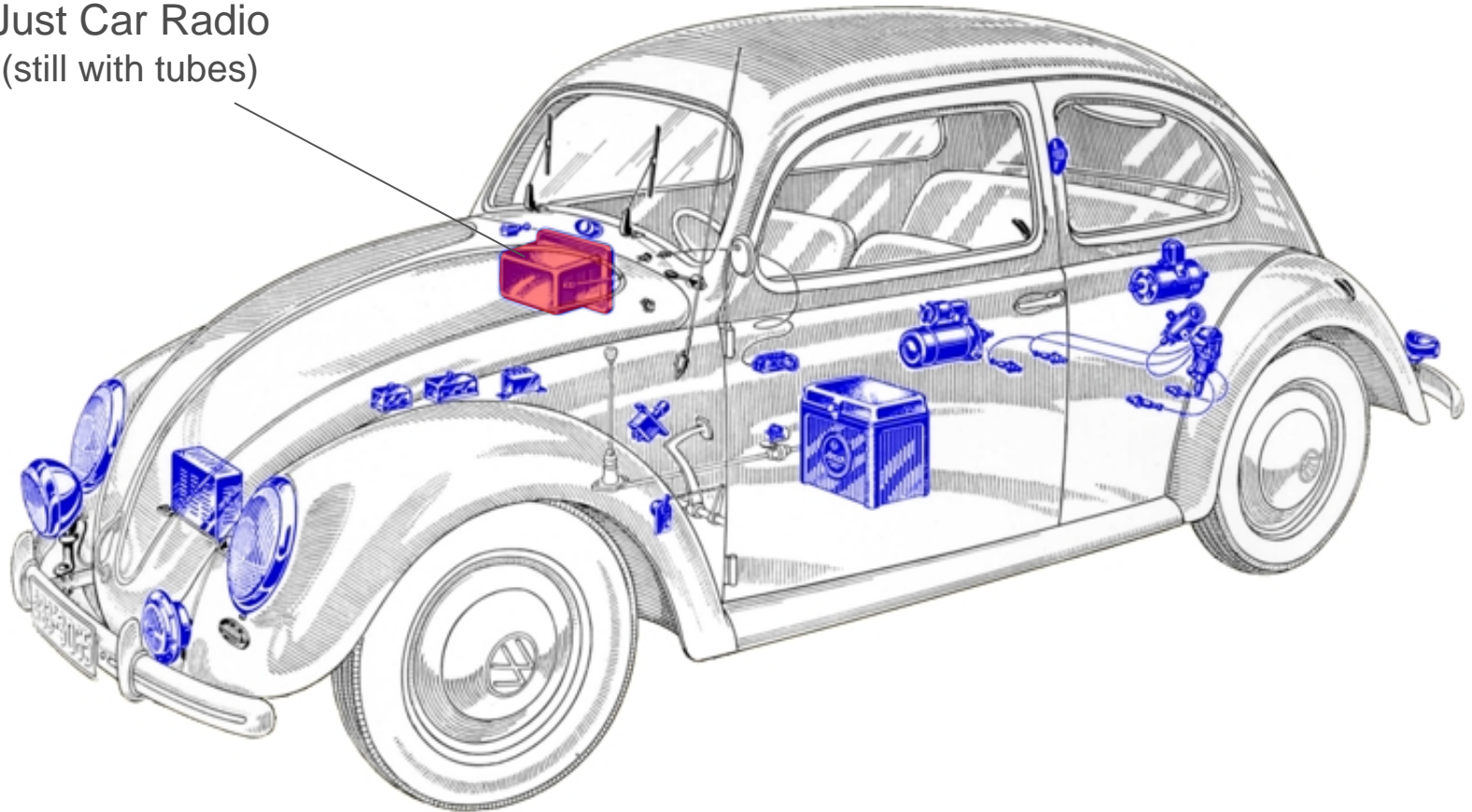
2007
MP3/PMP
+20% (Units)



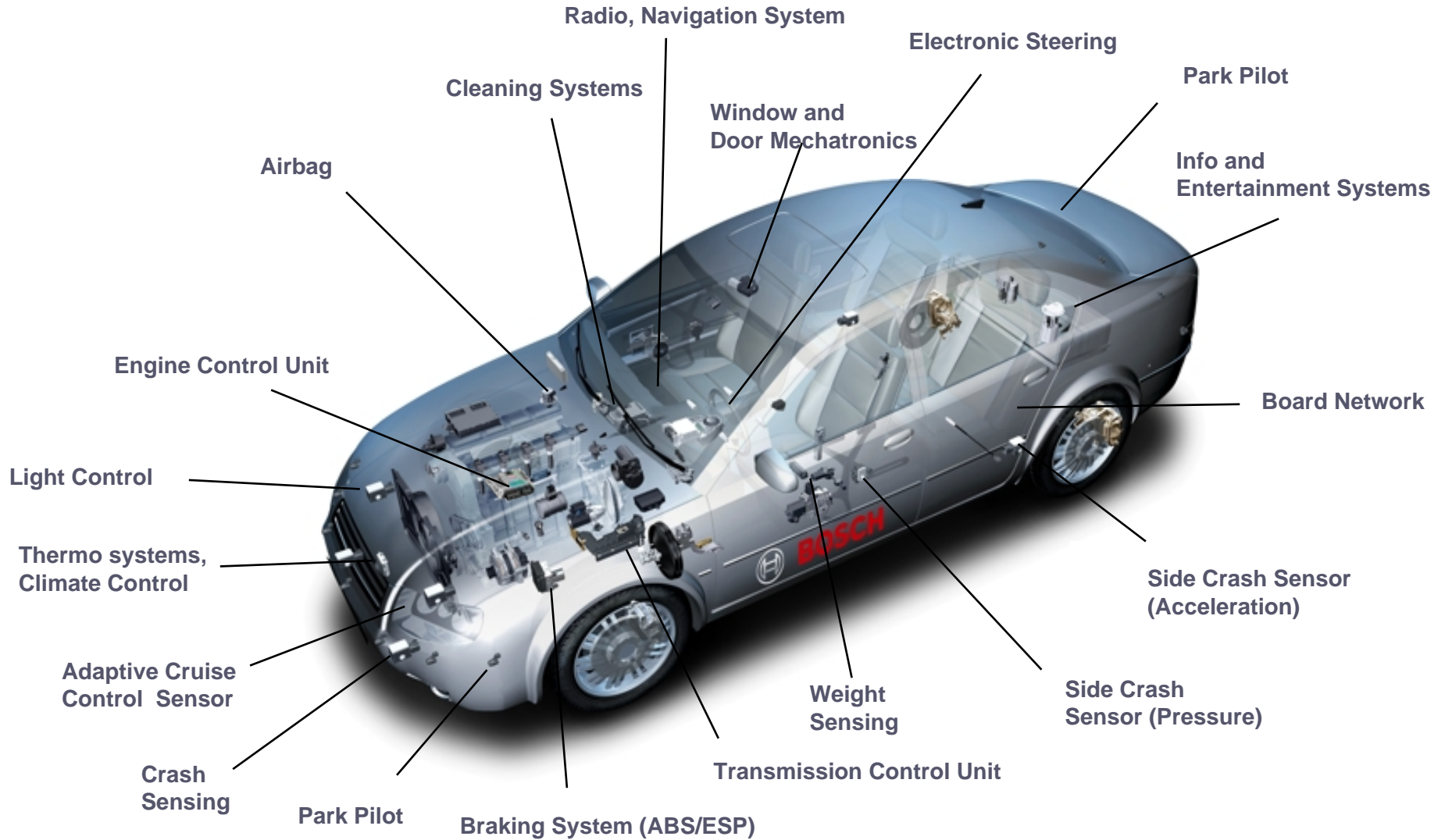
\$252.1B / +1.8%
2007

Automotive Electronics: Yesterday ...

Just Car Radio
(still with tubes)

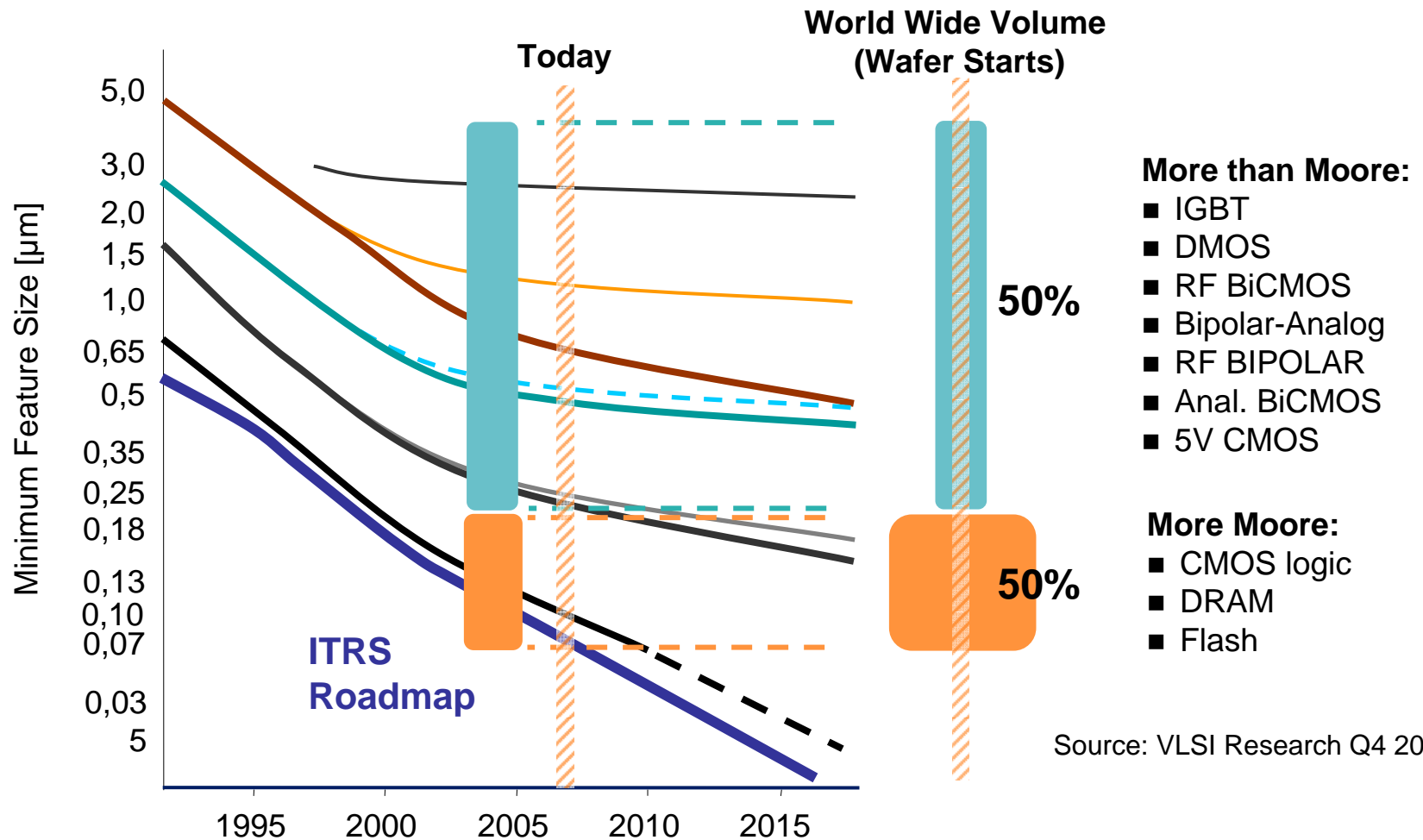


... and Today



Technologies for various applications scale with different speed

More than Moore contributes to 50% of world wide wafer volume



Source: Infineon

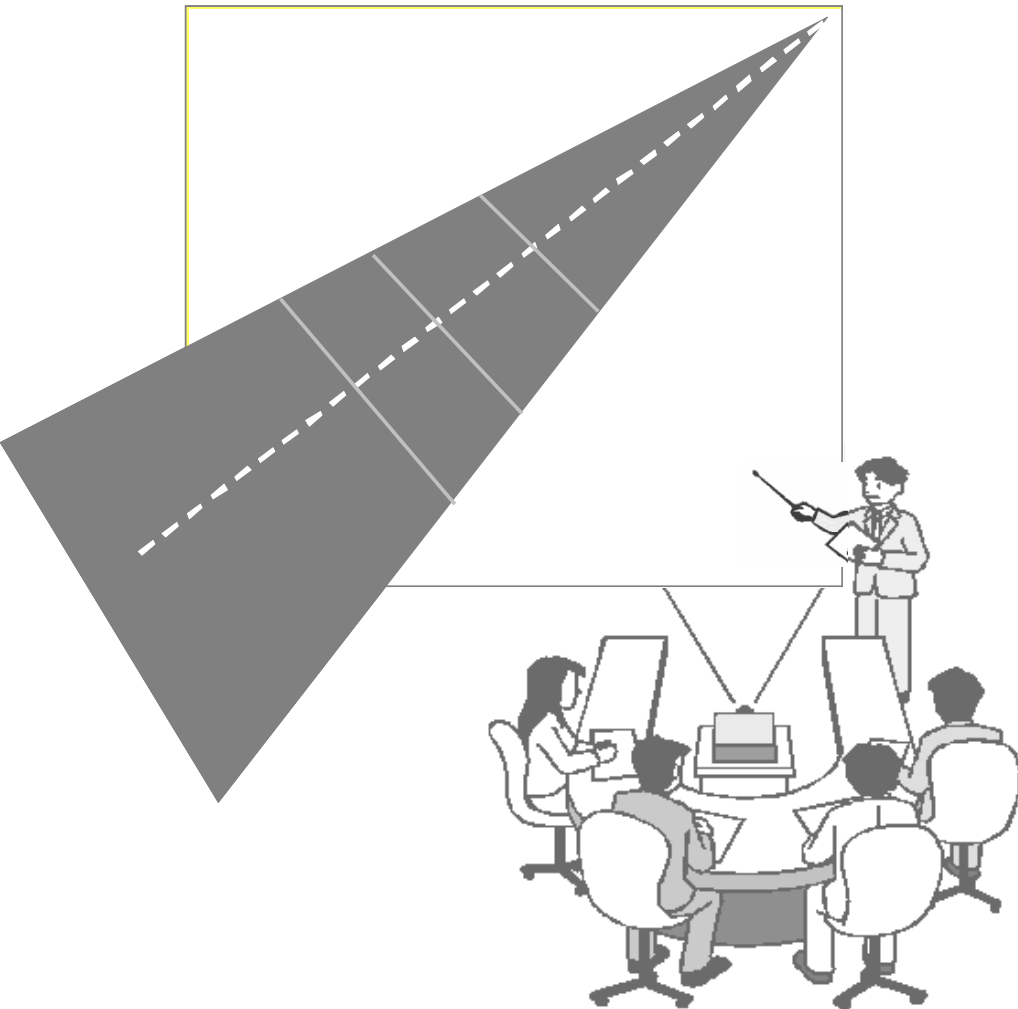
Source: VLSI Research Q4 2005

MORE THAN MOORE

Why should the ITRS care ?

PATRICK COGEZ
IRC – ESIA, Europe

More Moore : Planned technological targets

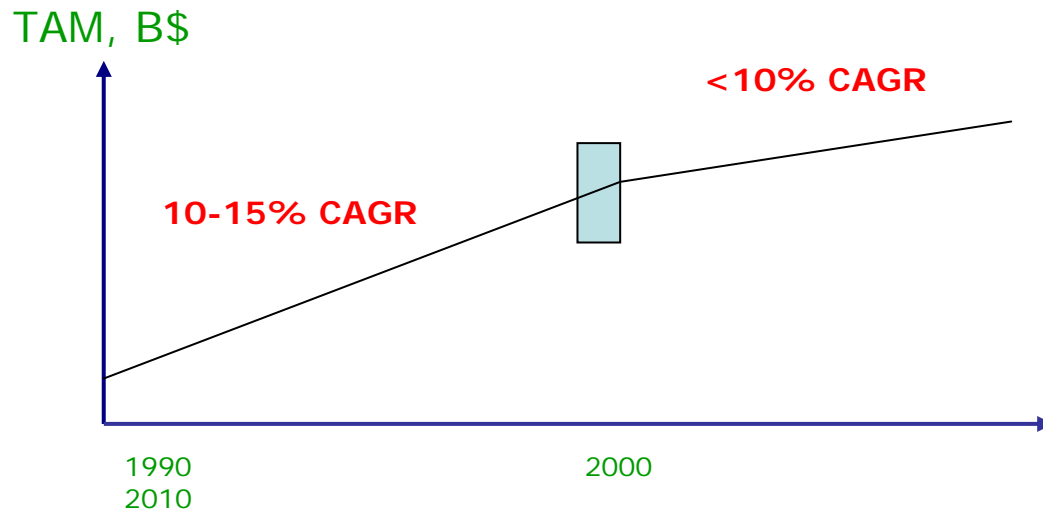


More than Moore : Which technologies ? Which trade-offs ? Coordinations for technological explorations?



Semiconductor Market Growth

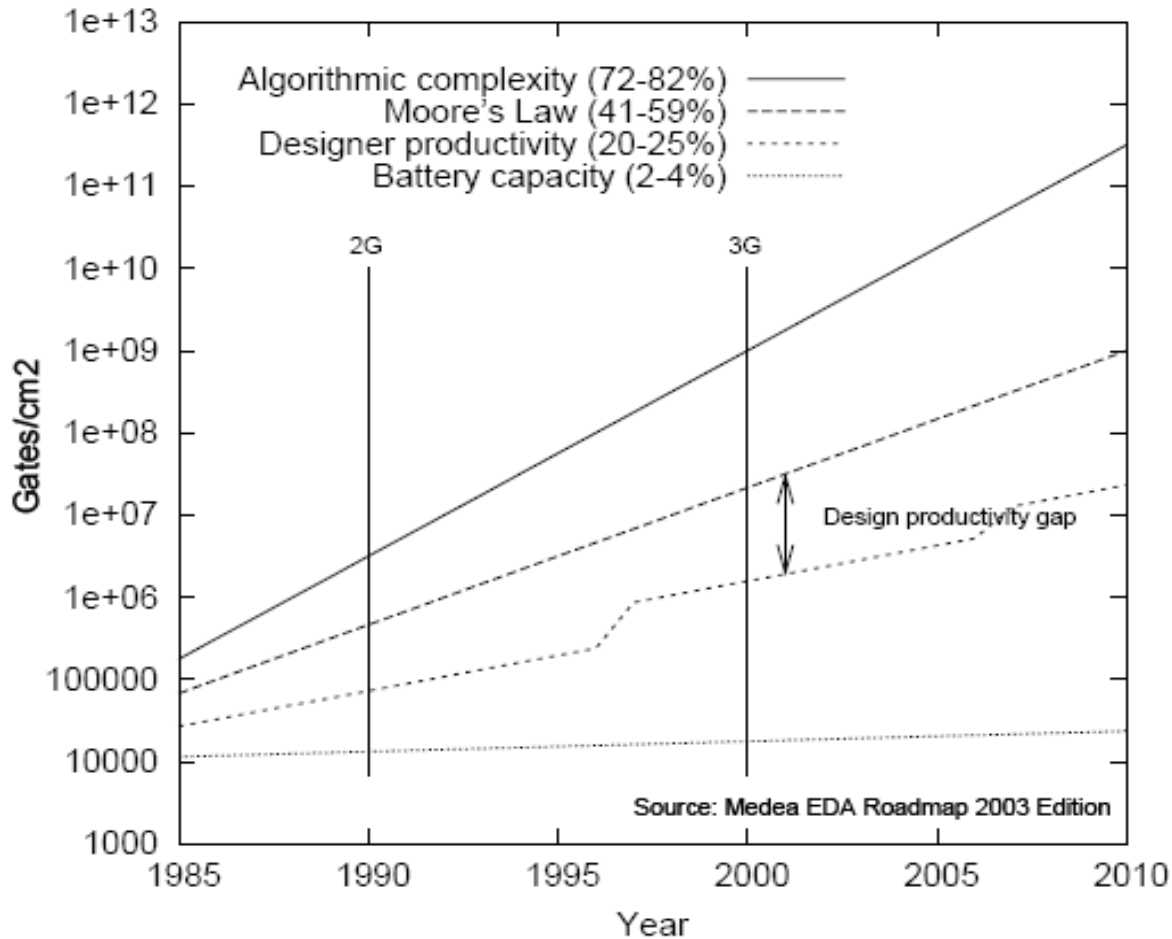
- From a historical CAGR of close to 15%, current visibility is at best 10% for the rest of the decade
 - R&D money is not unlimited
 - While R&D options are expanding



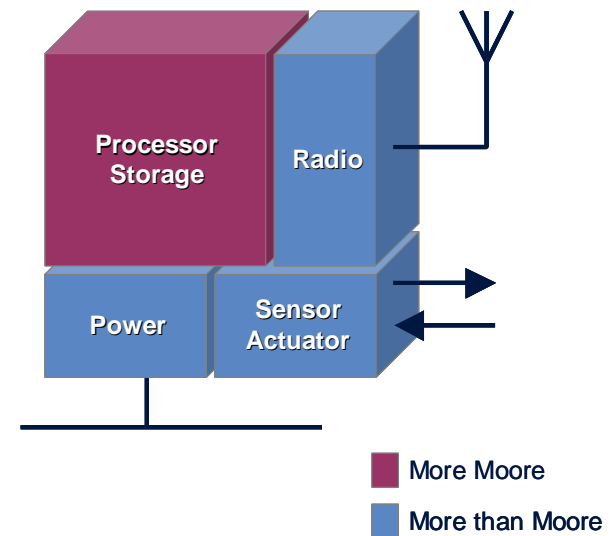
A renewed role for the ITRS

- ITRS goal
 - Provide research guidance for the industry
- In the past
 - Smaller was better, and cheaper
 - Criteria to gauge usefulness of research
 - ITRS role : identify the red brick walls
- Today
 - System performance no longer purely commanded by device performance
 - More Moore and More than Moore
 - What will bring more value to the end user ?
- ITRS role
 - Redefine the questions to be solved by the research community

"More than Moore" and design tools



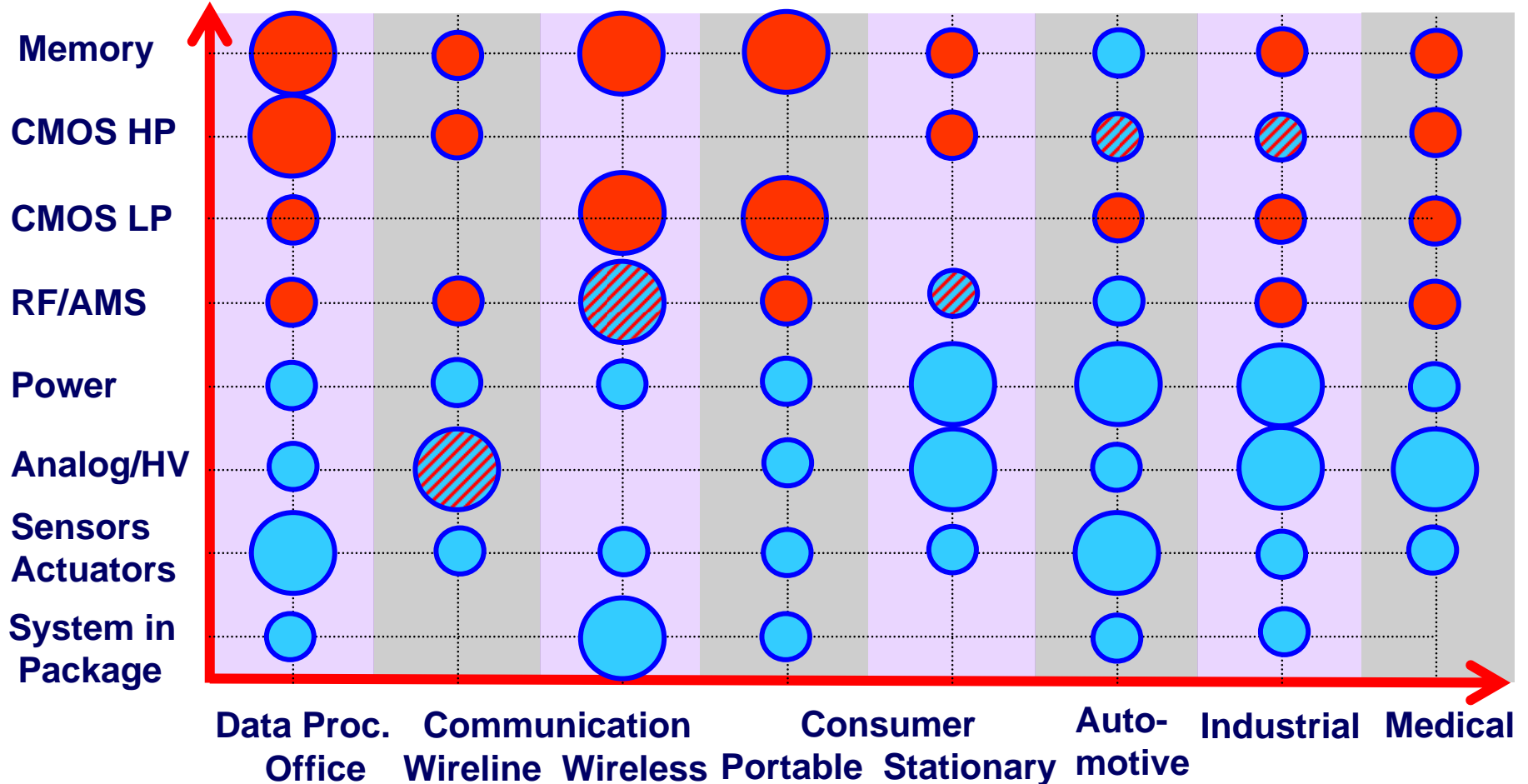
Society Needs:
Intelligent Compact Systems



Need for heterogeneous design platform

Market Drivers for Technology Roadmap

Technologies



Markets

Legend:



More Moore
(scaling)



More than Moore
(non-scaling)



mixed

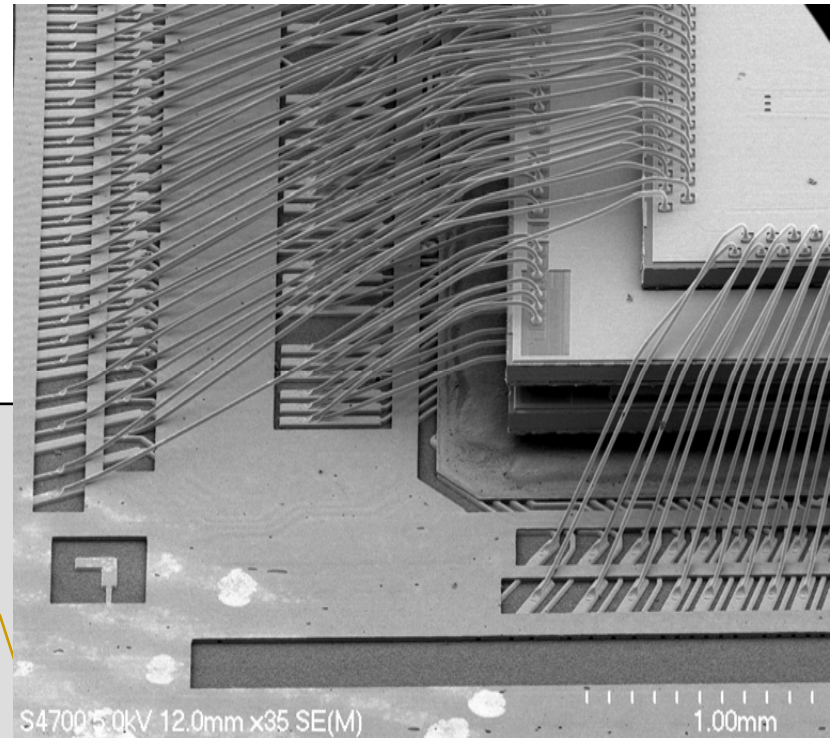
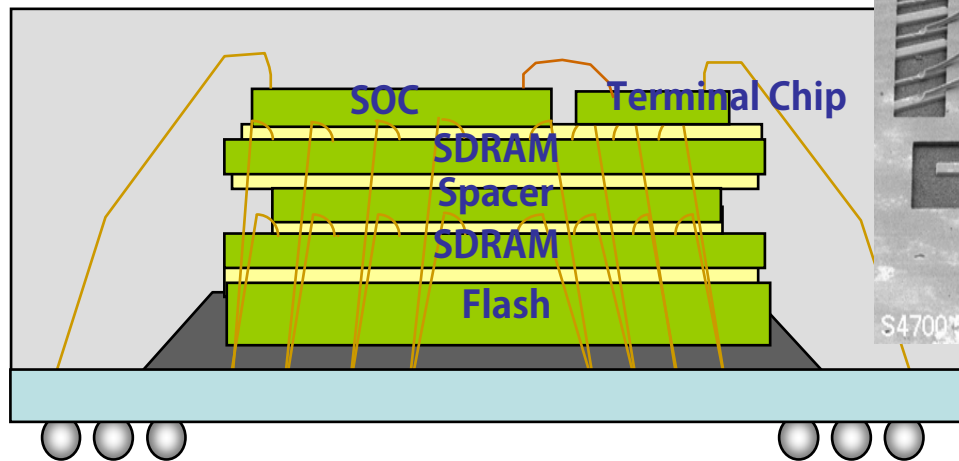
Bubble size
= driver impact

MORE THAN MOORE and
Beyond CMOS
*Technologies as Key
Components of
“Extended CMOS”*

HIDEMI ISHIUCHI
IRC -- JEITA, Japan

SiP Example for Digital Still Camera

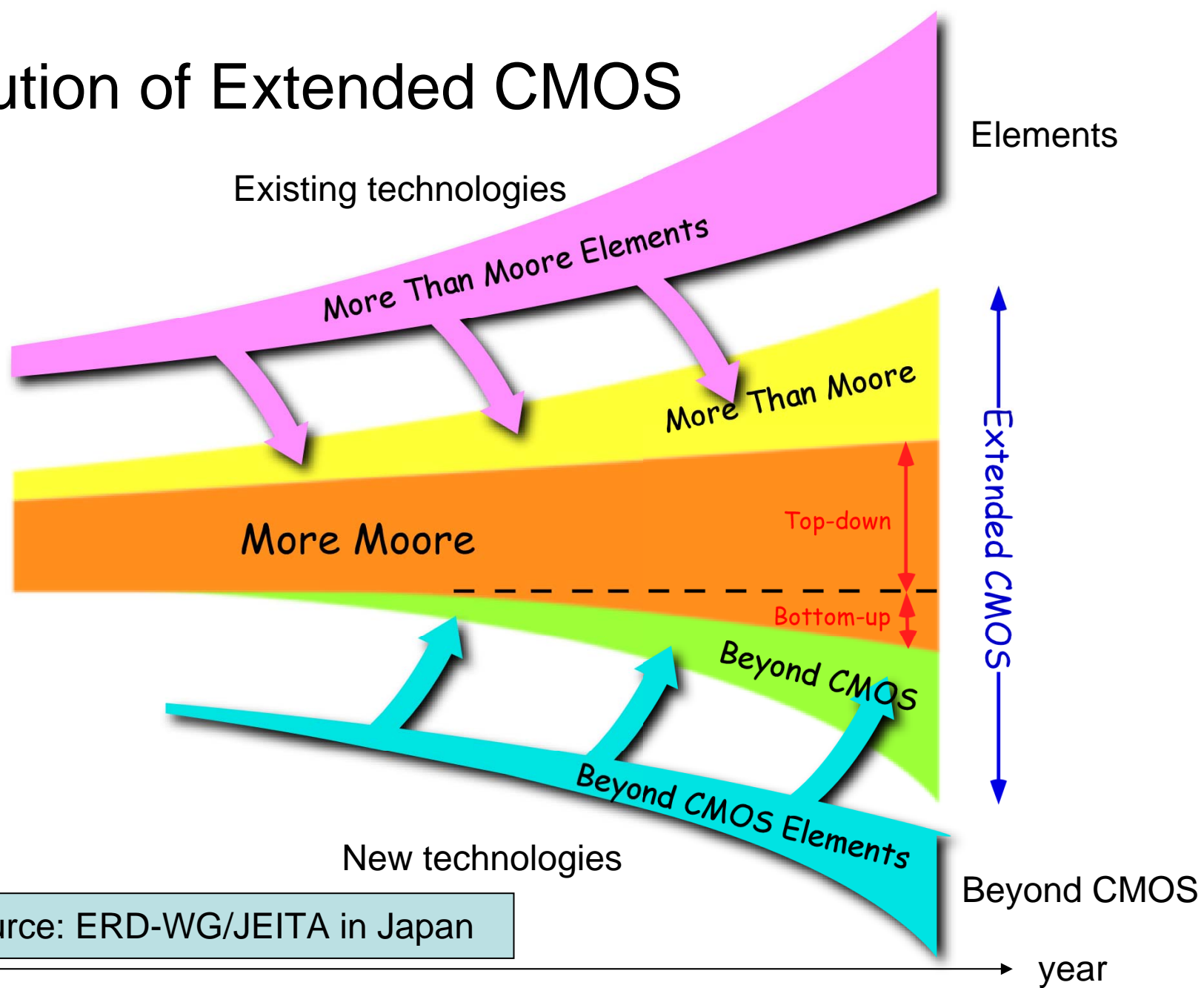
5 stacked chips



Courtesy of Renesas Technology Corp.

Source: A&P-WG/JEITA in Japan

Evolution of Extended CMOS



Source: ERD-WG/JEITA in Japan

More than Moore Elements and Beyond CMOS Elements

- More than Moore Elements
 - Analog CMOS, Passive Elements, Power Devices, Sensors & Actuators, Bio Chips, etc.
 - to be integrated into CMOS Technology
- Beyond CMOS Elements
 - Non-Charge-Based Devices: Quantum Devices, Spin-state Devices, Molecular Devices, etc.
 - to be integrated into CMOS Technology
 - or to be realized without using CMOS Technology

Extended CMOS

- Extended CMOS
 - “More than Moore Elements” and “Beyond CMOS Elements” are integrated into Scaled CMOS (“More Moore Technology”)
- Top-down
 - Fabrication methods using lithography and etching
- Bottom-up
 - Self-organized or Self-assembled

Panelists

MART GRAEF – International Roadmap Committee

PUSHKAR APTE – International Roadmap Committee

PATRICK COGEZ – International Roadmap Committee

HIDEMI ISHIUCHI – International Roadmap Committee

ALAN ALLAN – Overall Roadmap Technology Characteristics

BILL BOTTOMS – Assembly and Packaging

GEORGE BOURIANOFF – Emerging Research Devices

JUAN-ANTONIO CARBALLO – Design

HAROLD HOSACK – Interconnect

JACK PEKARIK – Wireless

PETER ZEITZOFF – Process Integration